

# **BCW31**

### **NPN General Purpose Amplifier**

- This device is designed for general purpose applications at collector currents to 300mA.
- Sourced from process 10.



1. Base 2. Emitter 3. Collector

# **Absolute Maximum Ratings \*** T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CEO}$	Collector-Emitter Voltage	32	V
V <sub>CBO</sub>	Collector-Base Voltage	32	V
V <sub>EBO</sub>	Emitter-Base Voltage	5.0	V
I <sub>C</sub>	Collector current (DC)	500	mA
T <sub>J</sub> , T <sub>sta</sub>	Operating and Storage Junction Temperature Range	-55 ~ +150	°C

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

- NOTES:

  1) These ratings are based on a maximum junction temperature of 150 degrees C.

  2) These are state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

### Electrical Characteristics T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
Off Charact	eristics		•	•	•	•
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> = 2.0mA, I <sub>B</sub> = 0	32			V
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	$I_{C} = 10\mu A, I_{B} = 0$	32			V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_C = 10\mu A, I_C = 0$	5.0			V
I <sub>CBO</sub>	Collector Cutoff Current	$V_{CB} = 32V, I_{E} = 0$ $V_{CB} = 32V, I_{E} = 0, T_{A} = 100^{\circ}C$			100 10	nA μA
On Charact	eristics			•		•
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 2.0mA, V <sub>CE</sub> = 5.0V	110		220	
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	$I_C = 10 \text{mA}, I_B = 0.5 \text{mA}$			0.25	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = 2.0mA, V <sub>CE</sub> = 5.0V	0.55		0.7	V
Small Signa	al Characteristics		•			
f <sub>T</sub>	Current Gain Bandwidth Product	$I_C = 2.0 \text{mA}, V_{CE} = 5.0 \text{V}$ f = 35MHz	200			
C <sub>obo</sub>	Output Capacitance	$V_{CB} = 10V, I_E = 0, f = 1.0MHz$			4.0	pF
NF	Noise Figure	$I_C = 0.2\text{mA}, V_{CE} = 5.0\text{V}$ $R_S = 2.0\text{k}\Omega, f = 1.0\text{kHz}$ $B_W = 200\text{Hz}$			10	dB

# Thermal Characteristics $T_A=25$ °C unless otherwise noted

Symbol	Parameter	Max.	Units
P <sub>D</sub>	Total Device Dissipation	350	mW
	Derate above 25°C	2.8	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient 357 °C/W		°C/W
Device mounted on FR-4PCB 40mm × 40mm × 1.5mm			

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# **Typical Characteristics**

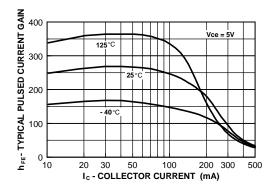


Figure 1. Typical Pulsed Current Gain vs Collector Current

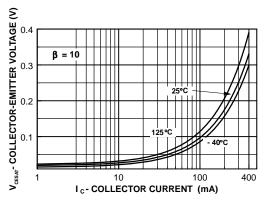


Figure 2. Collector-Emitter Saturation Voltage vs Collector Current

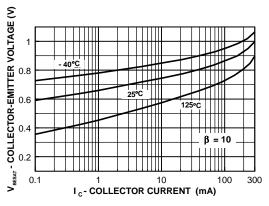


Figure 3. Base-Emitter Saturation Voltage vs Collector Current

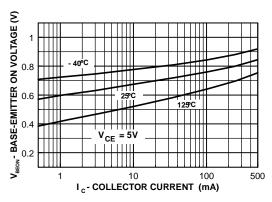


Figure 4. Base-Emitter On Voltage vs Collector Current

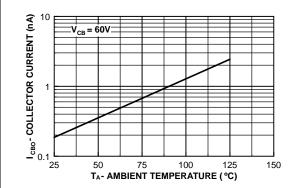


Figure 5. Collector-Cutoff Current vs Ambient Temperature

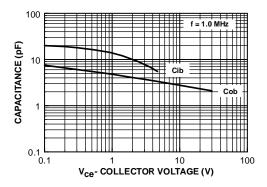


Figure 6. Input and Outtput Capacitance vs Reverse Voltage

# Typical Characteristics (Continued)

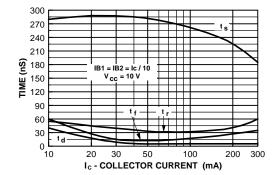


Figure 7. Switching Times vs Collector Current

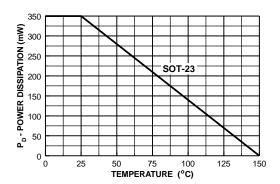
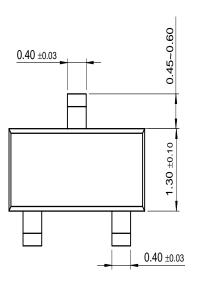
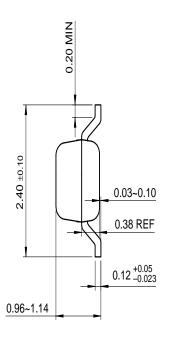


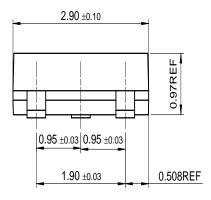
Figure 8. Power Dissipation vs Ambient Temperature

# **Package Dimensions**

# **SOT-23**







Dimensions in Millimeters

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CoolFET™	FASTr™	MicroFET™	PowerTrench <sup>®</sup>	SuperSOT™-6
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E <sup>2</sup> CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	$I^2C^{TM}$	$OCX^{TM}$	RapidConfigure™	UHC™
Across the board.	Around the world.™	OCXPro™	RapidConnect™	UltraFET <sup>®</sup>
The Power Franchise™		OPTOLOGIC <sup>®</sup>	SILENT SWITCHER®	VCX <sup>TM</sup>
Programmable Ad	ctive Droop™	OPTOPLANAR™	SMART START™	

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